

AN8585SH

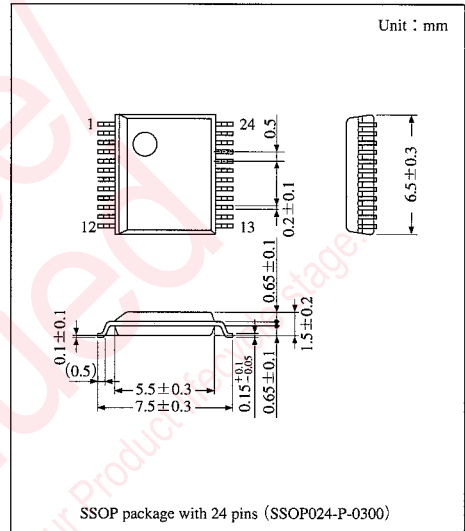
Cellular Telephone PLL IC Incorporating VCO

Overview

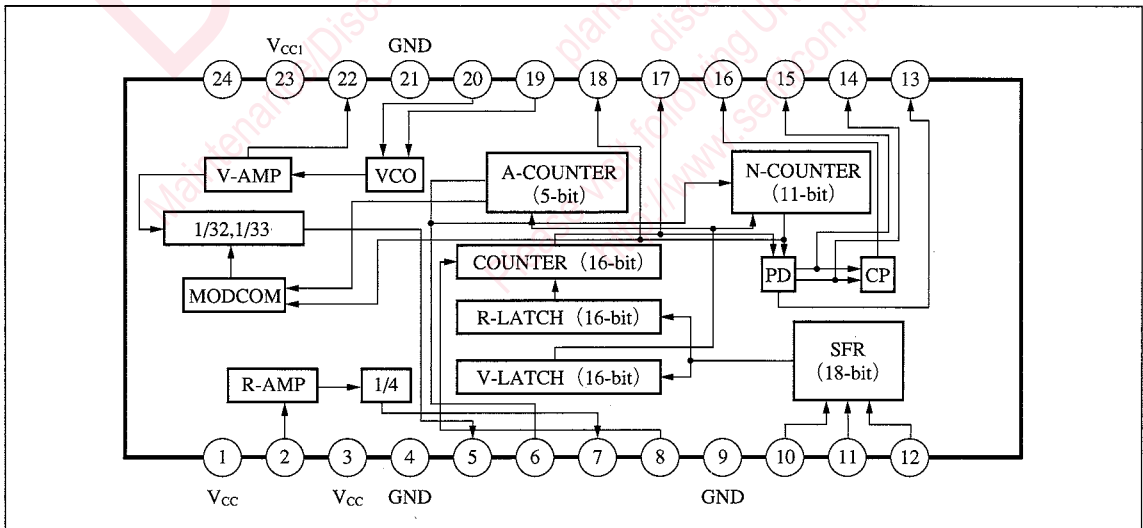
The AN8585SH is a mobile communication PLL IC incorporating a transmission VCO (TX IF : 145 MHz) .

Features

- VCO components and a PLL are integrated into an IC.
- Small-outline surface-mount package with 0.5 mm pitch
- Provides for a product with fewer components.



Block Diagram



Mobile
Communication

Pin Descriptions

Pin No.	Description	Pin No.	Description
1	V _{CC}	13	Lock detector output
2	Reference input	14	External phase detector output (1)
3	GND	15	External phase detector output (2)
4	V _{CC}	16	Phase detector output
5	VAR prescaler (1/32, 1/33) output	17	REF counter output
6	VAR counter input	18	VAR counter output
7	REF prescaler (1/4) output	19	RES1
8	REF counter input	20	RES2
9	GND	21	GND
10	Strobe input	22	RF output
11	Clock input	23	V _{CC1}
12	CH data input	24	Regulator output (2.5V)

Absolute Maximum Ratings (Ta = 25°C)

Parameter	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5	V
Supply current	I _{CC}	28	mA
Power dissipation	P _D	130	mW
Operating ambient temperature	T _{opr}	-20 to 75	°C
Storage temperature	T _{stg}	-55 to 125	°C

Recommended Operating Range

Parameter	Symbol	Range
Operating supply voltage range	V _{CC}	3.4V to 4.0V

Electrical Characteristics (Ta = 25 ± 2°C)

Parameter	Symbol	Condition	min	typ	max	Unit
Current consumption	I _{CC}	For f _{out} = 145M, Hz	—	16.5	19	mA
Reference input level	X _{in}	f _{in} = 10 ~ 20MHz, f _{out} = f _{in} /4	0.5	—	1.0	V _{P-P}
Power output	P _{out}	For f _{out} = 145MHz (P _{out} : f _{out} = 145MHzのレベル)	-12	-8.5	—	dBm
RF output level (1)	V _{O2}	For f _{out} = 145MHz, V _{O2} = P _{O2} - P _{out} (P _{O2} = 2 × f _{out})	—	—	-5	dBc
RF output level (2)	V _{O3}	For f _{out} = 145MHz, V _{O3} = P _{O3} - P _{out} (P _{O3} = 3 × f _{out})	—	—	-5	dBc
V _F voltage	V _F	For f _{out} = 145MHz	1.1	1.6	2.1	V

Note) Unless otherwise specified, V_{CC} = 3.7 V, f_{in} : 12.8MHz, and X_{in} : 0.7V_{P-P}.

Electrical Characteristics (Design Values for Reference) (Ta=25±2°C)

The following are design values for reference only (not guaranteed).

Parameter	Symbol	Condition	min	typ	max	Unit
S/N	S/N	f _{out} = 145MHz, f _{mod} = 1kHz, f _{DEV} = ±1.75kHz	40	50	—	dB
Distortion	THD	f _{out} = 145MHz, f _{mod} = 1kHz, f _{DEV} = ±1.5kHz	—	-45	-40	dB
Modulation sensitivity	V _R	f _{out} = 145MHz, f _{mod} = 1kHz, f _{DEV} = ±1.75kHz	—	-24	-21	dBs
Modulation f. characteristics	Mf	f _{out} = 145MHz, f _{mod} = 20Hz~4kHz (1kHz=0dB)	-3	0	1	dB
Power-ON rise time	T _L	f _{out} = 145MHz	30	40	50	msec
RF output level (3)	V _{O10}	f _{out} = 145MHz, V _{O10} = P _{O10} - P _{OUT} , P _{O10} = 10 × f _{OUT}	—	—	-38	dBc
RF output level (4)	V _{O11}	f _{out} = 145MHz, V _{O11} = P _{O11} - P _{OUT} , P _{O11} = 11 × f _{OUT}	—	—	-38	dBc
RF output level (5)	V _{O12}	f _{out} = 145MHz, V _{O12} = P _{O12} - P _{OUT} , P _{O12} = 12 × f _{OUT}	—	—	-38	dBc
C/N	C/N	f _{out} = 145MHz, 12.5kHz separation, 8kHz band	64	68	—	dB
Output leak current	I _{LCP}	V _{CC1} = 0V, V _{CP} = 3.7V, 0V	-1.0	0	1.0	μA
Output voltage (1)	V _{PCP}	V _{CC1} = 0V, I _{CP} = -1mA	2.9	3.35	3.8	V
Output voltage (2)	V _{NCP}	V _{CC1} = 0V, I _{CP} = 1mA	-0.10	0.17	0.80	V

Note) Unless otherwise specified, V_{CC} = 3.7V, reference input f_{in} : 12.8MHz, and X_{in} = 0.7V_{P-P}.

Usage Note

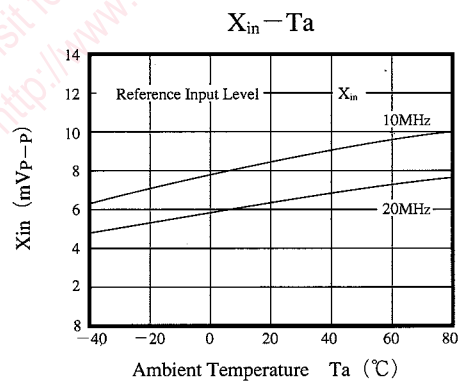
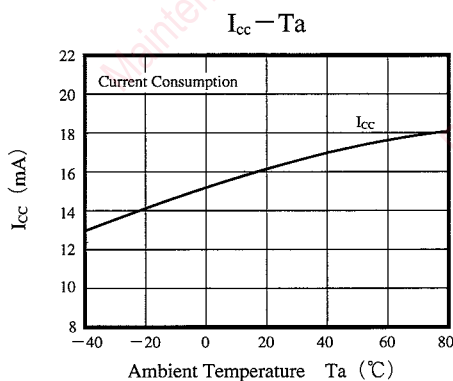
Surge Breakdown Levels

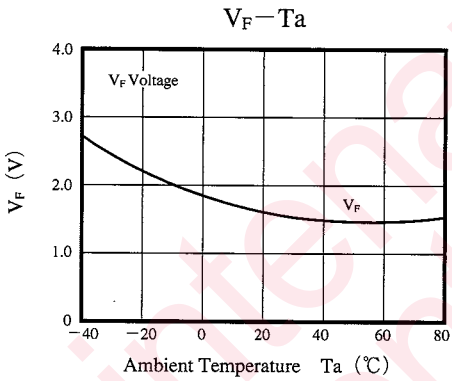
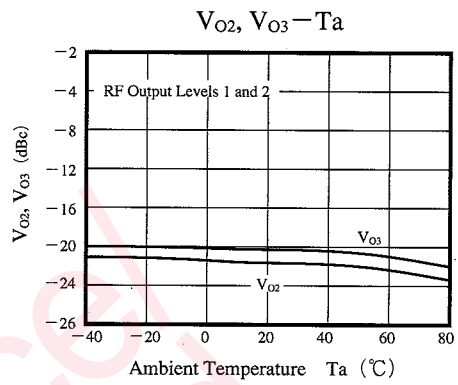
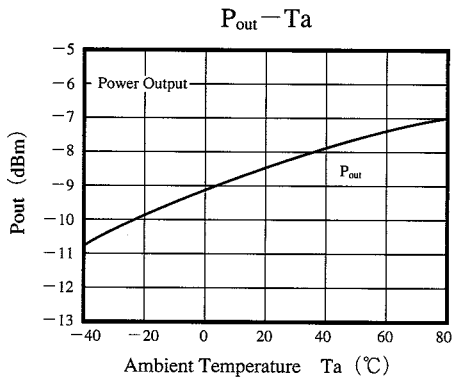
The following are design values for reference only (not guaranteed).

Condition : C = 200pF, R = 0Ω

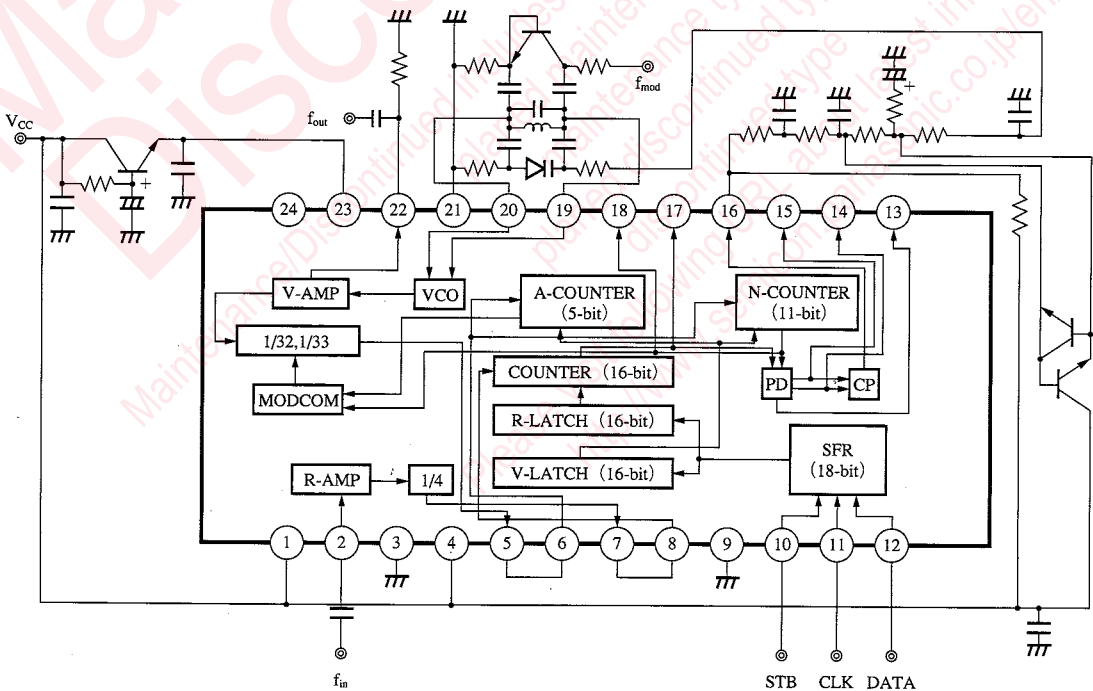
Pin No.	Positive breakdown level (V)
4	200 to 210
14	200 to 270
23	180 to 230

Characteristics Curve





Application Circuit



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